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YJD106506BQG2

Silicon Carbide Schottky Diode

Features

Positive temperature coefficient
Temperature-independent switching
Maximum working temperature at 175 °C
Unipolar devices and zero reverse recovery current
Zero forward recovery voltage
Essentially no switching losses
Reduction of heat sink requirements
High-frequency operation
Reduction of EMI

Typical Applications

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, electric car and charger.

Mechanical Data

Package: TO-263

Molding compound meets UL 94 V-0 flammability

rating, RoHS-compliant, halogen-free

Terminals: Tin plated leads **Polarity**: As marked

Maximum Ratings (T_c=25 °C Unless otherwise specified)

PARAMTETER	SYMBOL	UNIT	VALUE

Device marking code D106506B



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Electrical Characteristics

PARAMTETER	SYMBOL	UNIT	TEST CONDITIONS	Тур.	Max.
Forward voltage drap	V _F	>	I _F =6A, T _j =25°C	1.31	1.5
Forward voltage drop			I _F =6A, T _j =175°C	1.65	-
Reverse leakage current	I _R	μА	V _R =650V, T _j =25°C	0.5	25
Neverse leakage current			V _R =650V, T _j =175°C	5	-
Total capacitive charge	Q _C	nC	$V_R=400V, T_j=25^{\circ}C, QC = {}_{0}^{VR}C(V)dV$	25	-
	С	pF	V _R =0V, f=1MHZ	378	-
Total capacitance			V _R =200V, f=1MHZ	51	-
			V _R =400V, f=1MHZ	49	-
Capacitance Stored Energy	Ec	μJ	V _R =400V	3	-

Thermal Characteristics (Ta=25 °C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	Value
Thermal resistance	R _{J-C}	°C W	1.75

Typical Characteristics



Figure 1. Forward Characteristics

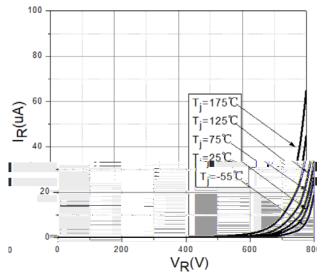


Figure 2. Reverse Characteristic



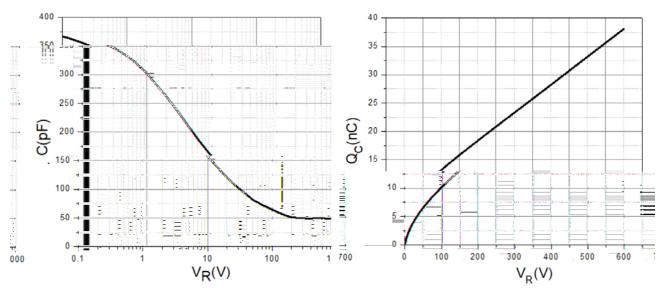
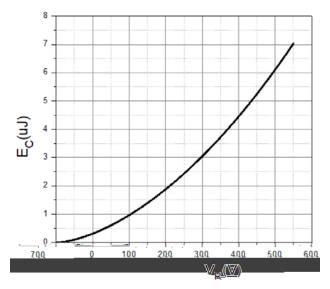
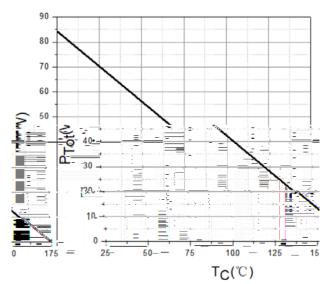


Figure 3. Capacitance vs. Reverse Voltage

Figure 4. Total Capacitance Charge vs. Reverse Voltage





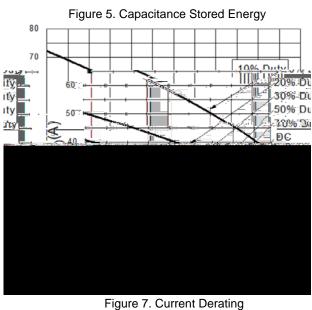


Figure 6. Power Derating

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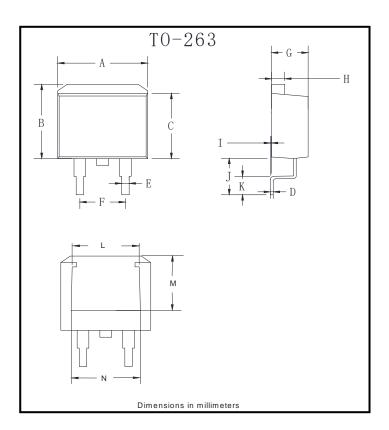
Figure 6. Power Derating

Figure 8. Iransient Thermal Impedance





Outline Dimensions



TO-263							
Dim	Min	Max					
А	9.5	11.5					
В	9.7	10.5					
С	8.4	9.0					
D	0.28	0.64					
Е	0.68	0.94					
F	4.55	5.6					
G	4.04	5.10					
Н	1.14	1.4					
I	0	0.2					
J	4.9	6.05					
K	1.79	2.79					
L	7.3	7.9					
М	6.2	6.8					
N	7.6	8.2					



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